2SB561

Silicon PNP Epitaxial

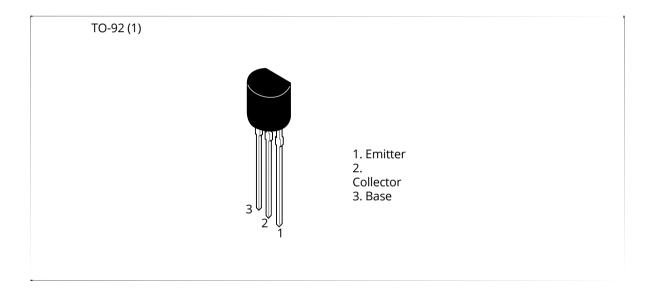
HITACHI

ADE-208-1023 (Z) 1st. Edition Mar. 2001

Application

- Low frequency power amplifier
- Complementary pair with 2SD467

Outline





Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

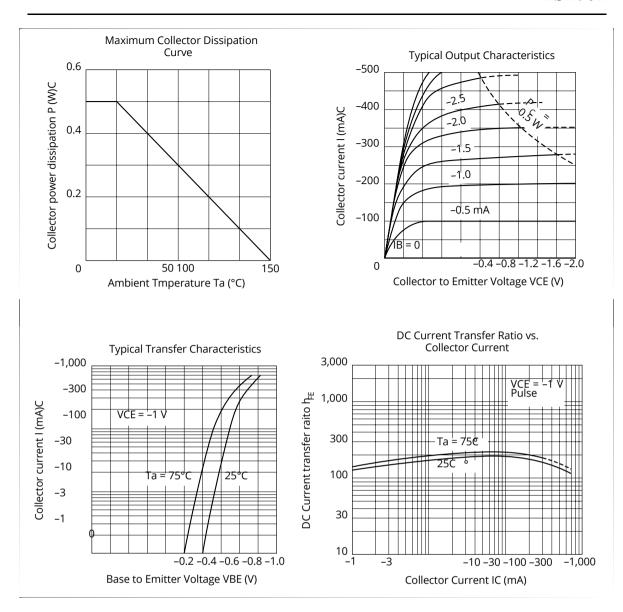
Item	Symbol	Ratings	Unit
Collector to base voltage	VCBO	- 25	V
Collector to emitter voltage	VCEO	-20	V
Emitter to base voltage	VEBO	- 5	V
Collector current	IC	-0.7	А
Collector peak current	iC(peak	-1.0	А
Collector power dissipation)	0.5	W
Junction temperature	PC	150	E
Storage temperature	Тј	-55 to +150	E
	Tstg		

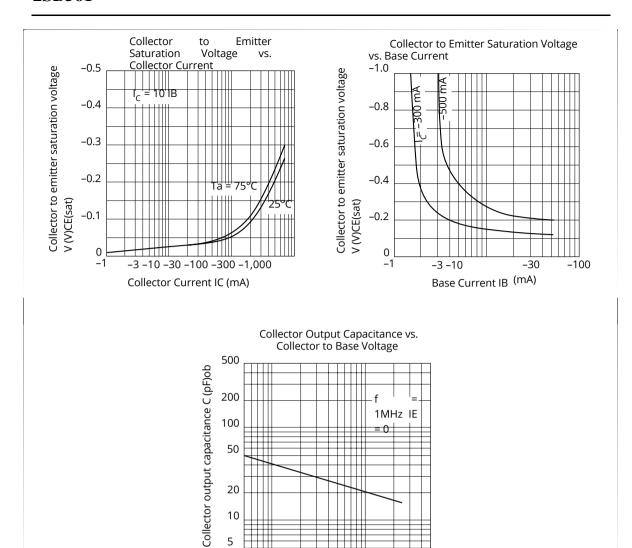
Electrical Characteristics $(Ta = 25^{\circ}C)$

Item Symbol Min Typ	Max	Unit	Test conditions
Collector to base breakdownV(BR)CBO-25- voltage	_	V	IC = -10 μA, IE = 0
Collector to emitter breakdownV(BR)CEO-20-		V	IC = −1 mA, RBE = ∞
voltage		.,	
Emitter to base breakdownV(BR)EBO-5—	_		IE = −10 μA, IC = 0
voltage	1.0	μA	VCB = -20 V, IE = 0
Collector cutoff currentICBO——	240	•	VCE = −1 V.
DC current transfer ratioh1FE*85—			IC = -0.15 A (Pulse test)
Collector to emitter saturationVCE(sat)—-0.2		.,	IC = −0.5 A, IB = −0.05 A
,	0.5	V	
voltage	0.5	V	VCE = -1 V, IC = -0.15 A
Base to emitter voltageVBE—–0.75	_	V	VCE = −1 V. IC = −0.15 A
Gain bandwidth productfT—350		MHz	•
Collector output capacitanceCob-20	1.0	pF	VCB = -10 V, IE = 0
•	1.0	•	f = 1 MHz
Note:1.The 2SB561 is grouped by hFE as follows.	_		

Note:1: The 20000113 grouped by the as follows

85 to 170120 to 240

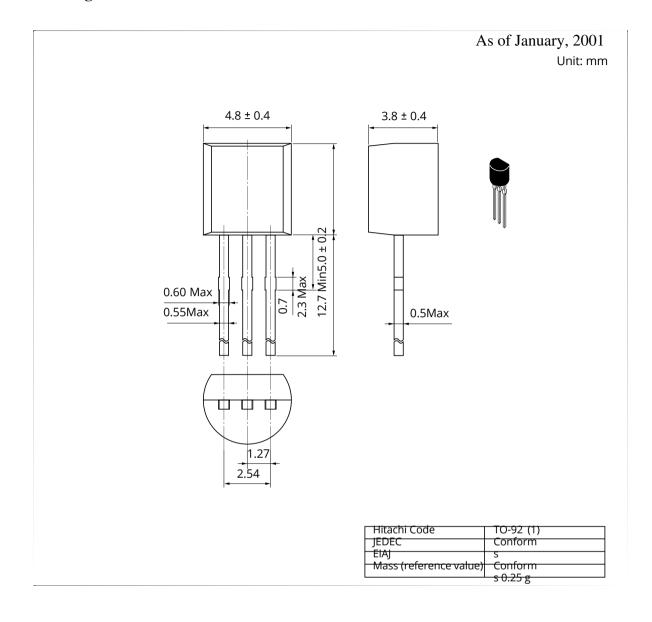




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-0.5 -1.0 -2 -5 -10 -20 -50 Collector Base Voltage VCB (V)

Package Dimensions



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